



nitrided metal silicide

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Semiconductor device and method of manufacturing the same - US ...

a gate electrode formed on the gate dielectric film and including a **nitrided metal silicide** layer which is partially crystallized; and ...

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Encapsulated MOS transistor gate structures and methods for making ...

The method of claim 3, wherein forming the **metal** or **metal silicide** comprises forming a **nitrided metal**, **metal aluminum nitride**, or **metal silicon nitride** ...

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Silicon **nitride** ceramics containing a **metal silicide** phase ...

Disclosed is a sintered ceramic product comprising (a) 20-98 percent by weight silicon **nitride**, (b) 1-80 percent by weight of a **silicide** of iron, ...

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Semiconductor structure including **metal nitride** and **metal silicide** ...

The present invention relates to a semiconductor structure including **metal nitride** and **metal silicide**, where a **metal silicide** layer is formed upon an active ...

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Silicon **nitride-metal** joints: phase equilibria in the systems Si ...

argon. Ternary powder compacts were prepared by mixing and cold pressing binary **metal silicide** powder. and silicon **nitride** powder. The green compacts were ...

www.springerlink.com/index/RJ16517376674753.pdf - [Similar pages](#) - [Note this](#)

(WO/1998/059366) **METAL** AND **METAL SILICIDE** NITRIDIZATION IN A HIGH ...

... of at least a portion of said layer of **metal** or **metal silicide** to produce a composition of **metal nitride** or **metal silicon nitride**, respectively. ...

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(WO/2000/014780) SEMICONDUCTOR PROCESSING METHOD, SEMICONDUCTOR ...

A semiconductor processing method comprising: forming a **metal silicide** layer ... over the **metal silicide** layer; and forming a layer of silicon **nitride** over ...

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High-performance **metal/silicide** antifuse (for CMOS technology ...

Histogram of programmed resistance for **metal/silicide** anti-. fuses. The area of the antifuse is 0.8 μm x 0.8 μm ; the dielectric is. oxide/**nitride** stack of ...

ieeexplore.ieee.org/iel1/55/4973/00192798.pdf?tp=&isnumber=&amnumber=192798 - [Similar pages](#) - [Note this](#)

Preparation of sialon-transition **metal silicide** composites

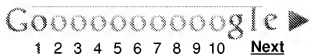
(1) Sialon-transition **metal silicides** composites with uni-. form microstructure can be prepared by reactions intering. of silicon **nitride** and transition **metal** ...

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IngentaConnect Texture of transition-**metal** boride, **nitride**, and ...

Texture of transition-**metal** boride, **nitride**, and **silicide** films produced by ion deposition. Authors: Ignatenko, P. I.; Goncharov, A.; Terpii, D. ...

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